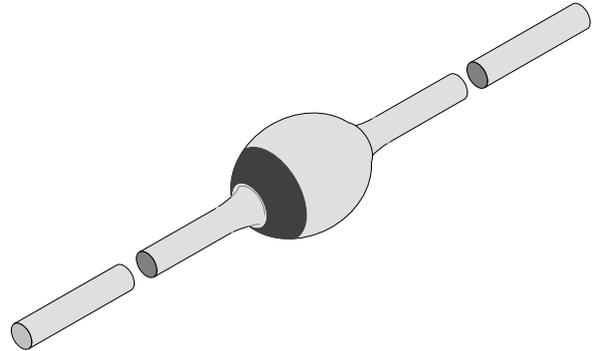


## Silicon Mesa Rectifiers

### Features

- Glass passivated junction
- Hermetically sealed package



94 9539

### Applications

Fast rectifier and switch for TV-line output circuits and switch mode power supply

### Absolute Maximum Ratings

$T_j = 25^\circ\text{C}$

Parameter	Test Conditions	Type	Symbol	Value	Unit
Reverse voltage= Crest working reverse voltage		BY203/12S	$V_{RWM}$	1200	V
		BY203/16S		1600	
		BY203/20S		2000	
Average forward current			$I_{FAV}$	250	mA
Peak forward surge current	$t_p=10\text{ms}$ half sinewave		$I_{FSM}$	20	A
Junction and storage temperature range			$T_j=T_{stg}$	-55...+150	$^\circ\text{C}$
Non repetitive reverse avalanche energy	$I_{(BR)R}=0.4\text{A}$		$E_R$	10	mJ

### Maximum Thermal Resistance

$T_j = 25^\circ\text{C}$

Parameter	Test Conditions	Symbol	Value	Unit
Junction ambient	$l=10\text{mm}$ , $T_L=\text{constant}$	$R_{thJA}$	45	K/W
	maximum lead length		100	

### Electrical Characteristics

$T_j = 25^\circ\text{C}$

Parameter	Test Conditions	Type	Symbol	Min	Typ	Max	Unit
Forward voltage	$I_F=200\text{mA}$ , $t_p/T=0.01$ , $t_p=0.3\text{ms}$		$V_F$			2.4	V
Reverse current	$V_R=700\text{V}$	BY203/12S	$I_R$			2	$\mu\text{A}$
	$V_R=1000\text{V}$	BY203/16S				2	
	$V_R=1200\text{V}$	BY203/20S				2	
Breakdown voltage	$I_R=100\mu\text{A}$ , $t_p/T=0.01$ , $t_p=0.3\text{ms}$	BY203/12S	$V_{(BR)}$	1200			V
		BY203/16S		1600			
		BY203/20S		2000			
Reverse recovery time	$I_F=0.5\text{A}$ , $I_R=1\text{A}$ , $i_R=0.25\text{A}$		$t_{rr}$			300	ns

Characteristics ( $T_j = 25^\circ\text{C}$  unless otherwise specified)

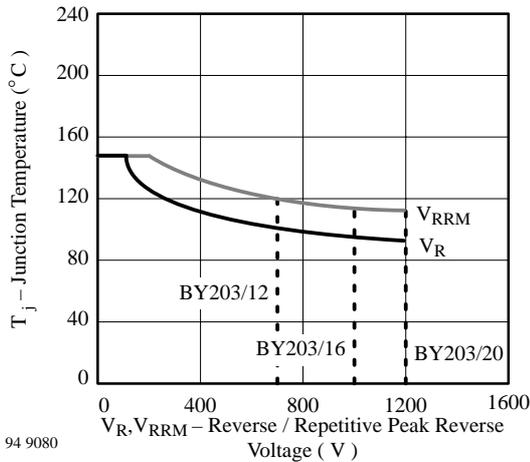


Figure 1. Junction Temperature vs. Reverse/Repetitive Peak Reverse Voltage

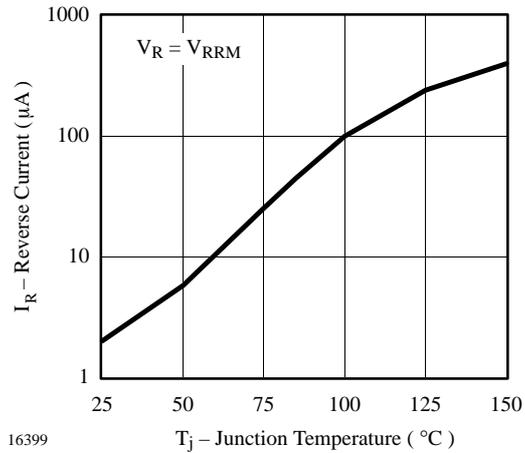


Figure 4. Reverse Current vs. Junction Temperature

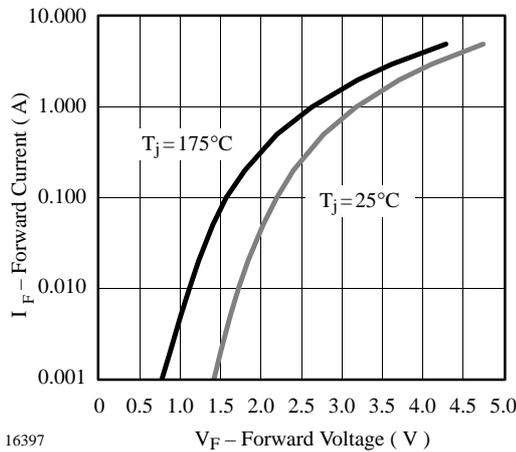


Figure 2. Forward Current vs. Forward Voltage

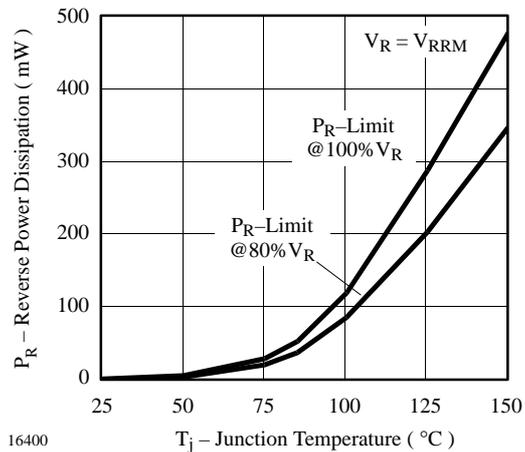


Figure 5. Max. Reverse Power Dissipation vs. Junction Temperature

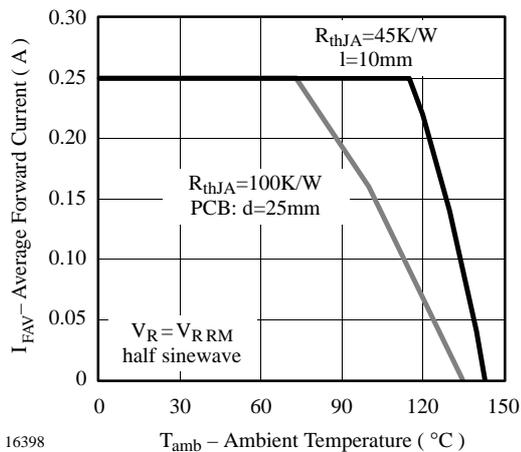


Figure 3. Max. Average Forward Current vs. Ambient Temperature

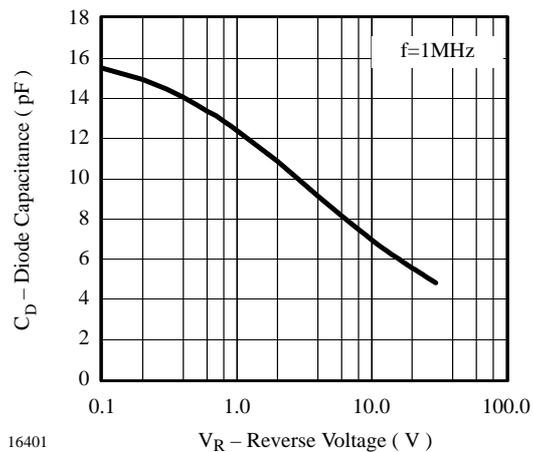
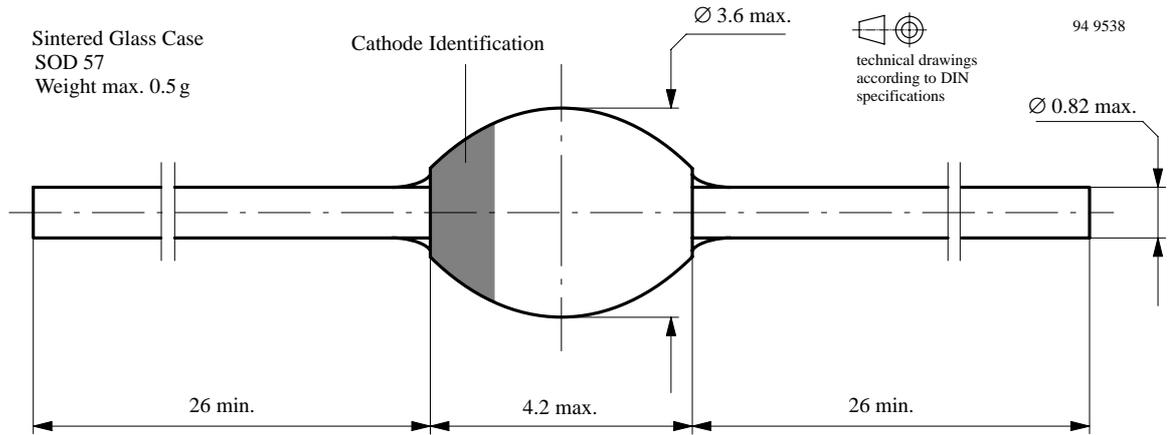


Figure 6. Diode Capacitance vs. Reverse Voltage

**Dimensions in mm**



### Ozone Depleting Substances Policy Statement

It is the policy of **Vishay Semiconductor GmbH** to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

**Vishay Semiconductor GmbH** has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

**Vishay Semiconductor GmbH** can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

**We reserve the right to make changes to improve technical design and may do so without further notice.**

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay-Telefunken products for any unintended or unauthorized application, the buyer shall indemnify Vishay-Telefunken against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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